L	Hits	Search Text	DB	Time stamp
Number				
1	0	vertical adj transistor and reverse adj	USPAT;	2004/06/25
		"T" and (trench or via) and gate	EPO; JPO;	09:37
			DERWENT	
2	0	reverse adj "T" and (trench or via) and	USPAT;	2004/06/25
		gate and isolation adj layer	EPO; JPO;	09:38
			DERWENT	
3	0	reverse adj "T-shaped" and (trench or	USPAT;	2004/06/25
		via) and gate and isolation adj layer	EPO; JPO;	09:38
			DERWENT	
4	0	reverse adj T-shaped and (trench or via)	USPAT;	2004/06/25
		and gate and isolation adj layer	EPO; JPO;	09:38
			DERWENT	
5	0	reverse adj T adj shaped and (trench or	USPAT;	2004/06/25
		via) and gate and isolation adj layer	EPO; JPO;	09:42
			DERWENT	
6	0	reverse and (trench or via) and gate and	USPAT;	2004/06/25
		isolation adj layer and trench adj top	EPO; JPO;	09:43
		adj oxide	DERWENT	
7	5	reverse and (trench or via) and gate and	USPAT;	2004/06/25
		isolation and trench adj top adj oxide	EPO; JPO;	09:43
			DERWENT	